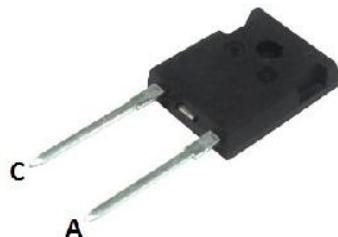
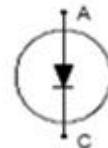


**Fast Recovery 15A, 600V Epitaxial Diodes,
in TO247 package**

APPLICATIONS

- Freewheeling diode (FWD)
- Snubber diode
- Clamp diode
- Power factor correction (PFC)
- Plating power supply
- Ultrasonic cleaner and welder
- Converter and chopper
- Uninterruptible power supplies
- High speed rectifiers
- Inductive heating and melting applications



FEATURES

- Ultrafast recovery time
- Soft recovery characteristics
- Low recovery loss
- Low forward voltage
- High surge current capability
- Low leakage current
- Pb-free finished; **RoHS compliant**

MAXIMUM RATINGS, at $T_C = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Units
Repetitive peak reverse voltage	V_{RRM}	600	V
Average forward current $T_C = 110^\circ\text{C}$	$I_{F(AV)}$	15	A
Surge non-repetitive forward current $T_J = 45^\circ\text{C}$, $t_p = 10 \text{ ms}$, 50Hz, Sine	I_{FSM}	150	
Power dissipation	P_D	83	W
Operating junction and storage temperature	T_J, T_{stg}	-40... +150	$^\circ\text{C}$

Thermal Characteristics

Parameter	Symbol	Max. Value	Units
Characteristics			
Thermal resistance, junction to case	R_{thJC}	1.5	$^\circ\text{C/W}$

Electrical Characteristics, at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Static Characteristics					
Reverse leakage current $V_R = 600\text{V}$	I_R	-	-	10 250	μA
$V_R = 600\text{V}, T_j = 150^\circ\text{C}$		-	-		
Forward voltage drop $I_F = 15\text{A}$	V_F	-	1.5 1.2	1.8	V
$I_F = 15\text{A}, T_j = 150^\circ\text{C}$		-		-	

Electrical Characteristics, at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Dynamic Characteristics					
Reverse recovery time $V_R = 300\text{V}, I_F = 15\text{A}, di_F/dt = -200\text{A}/\mu\text{s}$	t_{rr}	-	49 130	-	ns
$V_R = 300\text{V}, I_F = 15\text{A}, di_F/dt = -200\text{A}/\mu\text{s}, T_j = 150^\circ\text{C}$		-		-	
Reverse recovery charge $V_R = 300\text{V}, I_F = 15\text{A}, di_F/dt = -200\text{A}/\mu\text{s}$	Q_{rr}	-	40 640	-	nC
$V_R = 300\text{V}, I_F = 15\text{A}, di_F/dt = -200\text{A}/\mu\text{s}, T_j = 150^\circ\text{C}$		-		-	
Maximum reverse recovery current $V_R = 300\text{V}, I_F = 15\text{A}, di_F/dt = -200\text{A}/\mu\text{s}$	I_{rrm}	-	2.5 10	-	A
$V_R = 300\text{V}, I_F = 15\text{A}, di_F/dt = -200\text{A}/\mu\text{s}, T_j = 150^\circ\text{C}$		-		-	

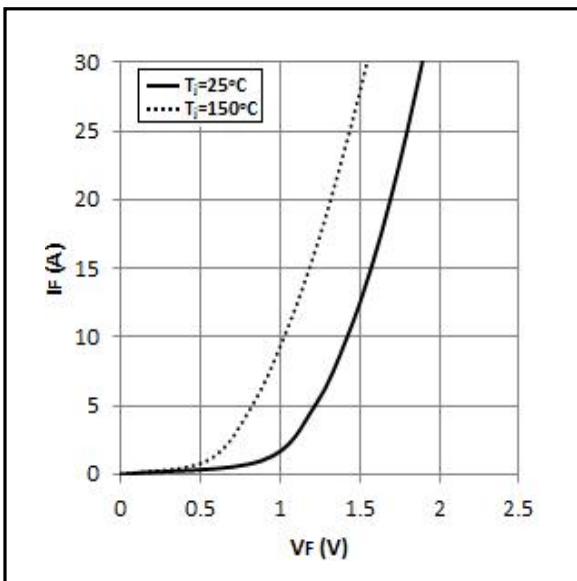
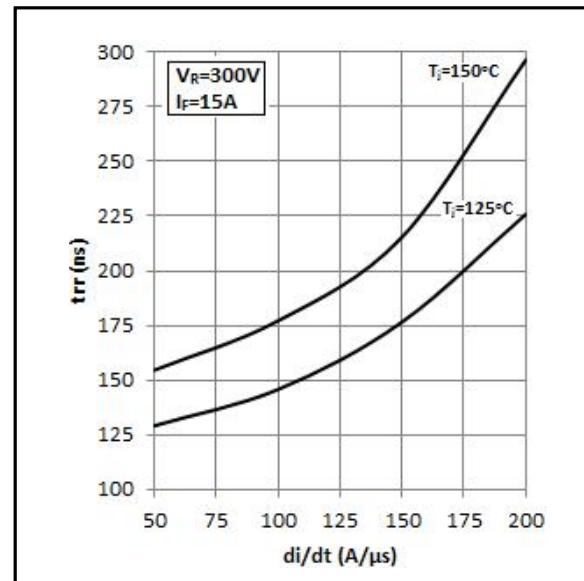
Figure 1 – Typical Forward voltage drop vs forward current

Figure 2 – Reverse recovery time vs diF/dt


Figure 3 – Reverse recovery charge vs di/dt

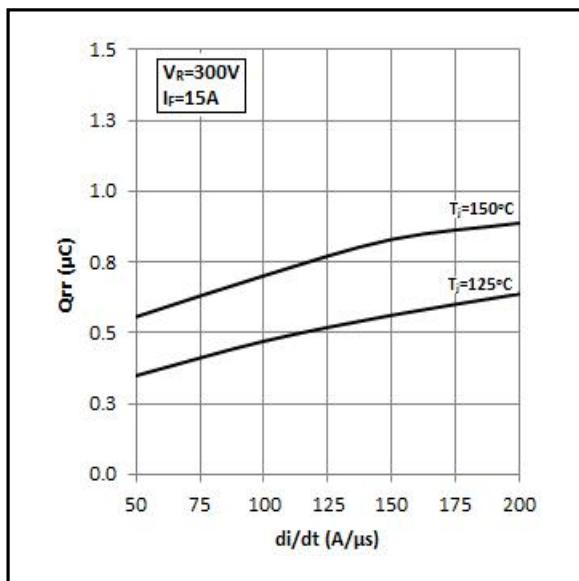


Figure 4 – Maximum reverse recovery current vs di_F/dt

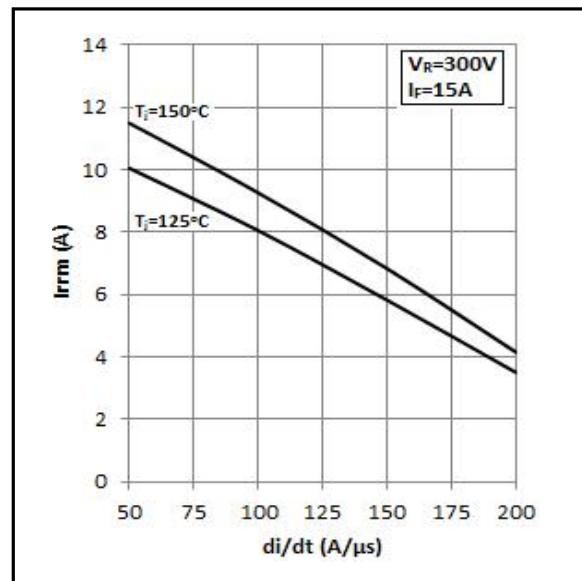
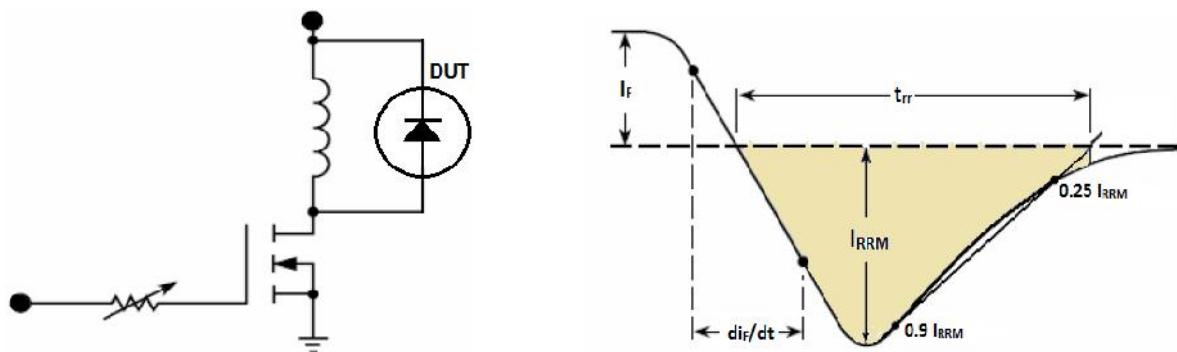
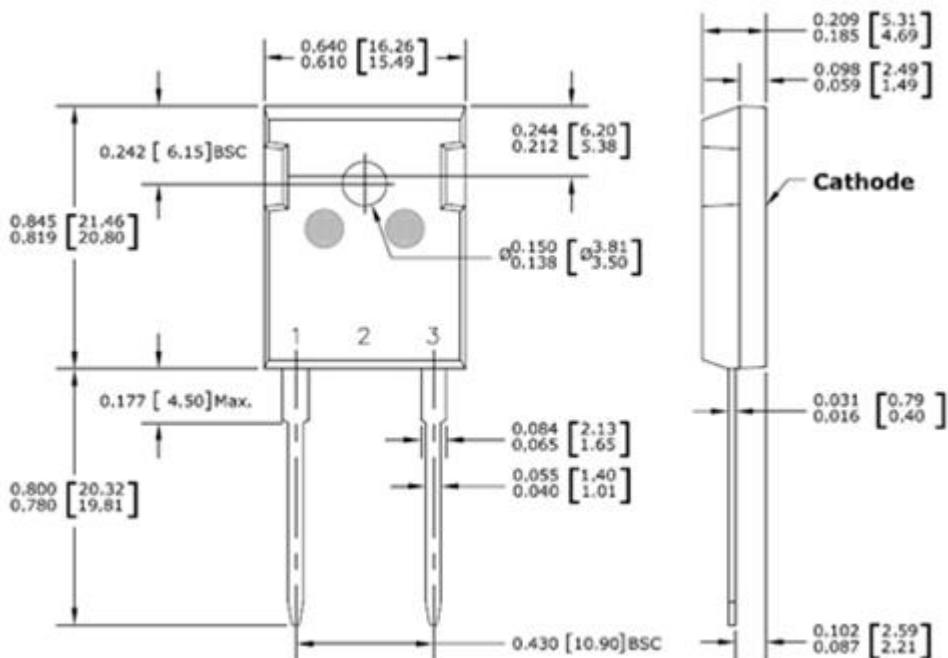


Figure 5 – Diode Reverse Recovery Test Circuit and Waveform



Package Outline Drawing



Disclaimer

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**